Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-811-4839

Inclosure Material:

Metal

Overall Length:

0.450 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 reverse voltage, peak

Current Rating Per Characteristic:

25.00 amperes forward current, average absolute

Power Rating Per Characteristic:

30.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

190.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Specification Data:

80131-release2574 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0